

High voltage fast-switching NPN Power Transistor

General features

- NPN Transistor
- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed
- Fully characterized at 125 °C
- In compliance with the 2002/93/EC European Directive

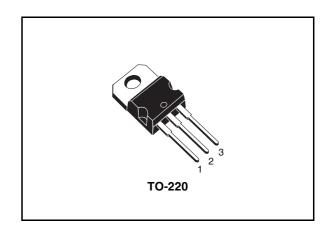
Description

The device is manufactured using high voltage Multi-Epitaxial Planar technology for high switching speeds and medium voltage capability.

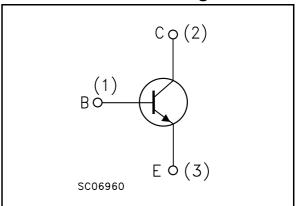
It uses a Cellular Emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

Applications

- Electronic ballast for fluorescent lighting
- Dedicated for PFC solution in HF ballast halfbridge voltage fed



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing
BUL705	BUL705	TO-220	Tube

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BUL705 Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	700	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
V _{EBO}	Emitter-base voltage (I _C = 0)	10	V
I _C	Collector current	5	Α
I _{CM}	Collector peak current (t _P < 5ms)	10	Α
I _B	Base current	2	Α
I _{BM}	Base peak current (t _P < 5ms)	4	Α
P _{tot}	Total dissipation at T _c = 25°C	80	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max	1.56	°C/W
R _{thj-amb}	Thermal resistance junction-amb max	62.5	°C/W

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Electrical characteristics BUL705

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 3. Electrical characteristics

Symbol	Parameter Test Conditions		Min.	Тур.	Max.	Unit	
I _{CES}	Collector cut-off current (V _{BE} =-1.5V)	V _{CE} =700V V _{CE} =700V	T _j =125°C			100 500	μ Α μ Α
I _{CEO}	Collector cut-off current (I _B =0)	V _{CE} =400V				250	μА
V _{EBO}	Emitter-base voltage (I _C = 0)	I _E =10mA		10			V
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C =100mA	L =25mH	400			٧
V _{CE(sat)} (1)	Collector-emitter saturation voltage	I _C =2A I _C =3A I _C =4A	$I_B = 0.4A$ $I_B = 0.6A$ $I_B = 1A$			0.4 0.6 0.8	V V V
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C =2A I _C =3A	I _B =0.4A I _B =0.6A			1.1 1.2	V V
h _{FE}	DC current gain	I _C =10mA I _C =2A	V _{CE} =5V V _{CE} =5V	10 16		32	
t _s	Resistive load Storage time	$V_{CC} = 250V$ $I_{B1} = -I_{B2} = 0.4A$ (see fig.12)	_	2.4		3.5	μs
t _s	Inductive load Storage time Fall time	I_C =2A $V_{BE(off)}$ =-5V V_{clamp} =250V (see fig.13)			0.7 50	1.4 100	μs ns
t _s	Inductive load Storage time Fall time	I_C =2A $V_{BE(off)}$ =-5V V_{clamp} =250V T_j =125°C	L =200μH		1 75		μs ns

Note (1) Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

Figure 2. Derating Curve

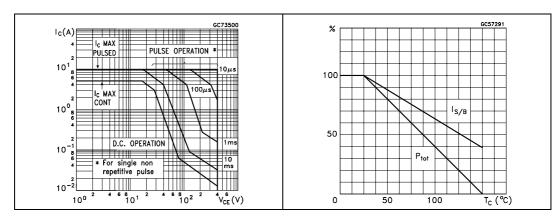


Figure 3. DC current gain

Figure 4. DC current gain

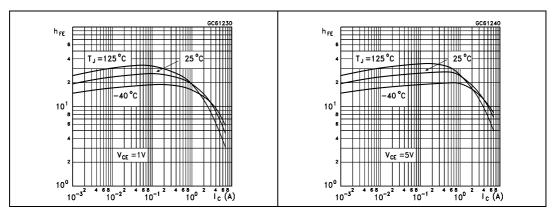


Figure 5. Collector-emitter saturation Figure 6. Base-emitter saturation voltage voltage

Voltage

V_{BE}(scr)
(V)

T_J = 25 °C

T_J = 25 °C

T_J = 125 °C

N_{FE} = 5

0.4

10⁻¹

2 4 6 8 10⁰

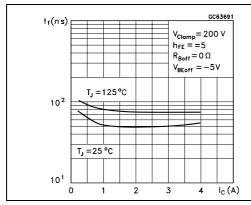
2 4 6 8 1c (A)

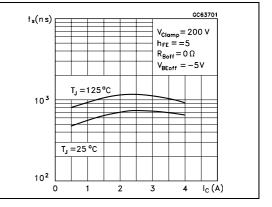
V_{CE} (sat) (V) 6 4 h_{FE} = 5 10⁰ 8 4 T_J = 25°C T_J = 25°C T_J = 125°C T_J = 125°C

Electrical characteristics BUL705

Figure 7. Inductive load fall time

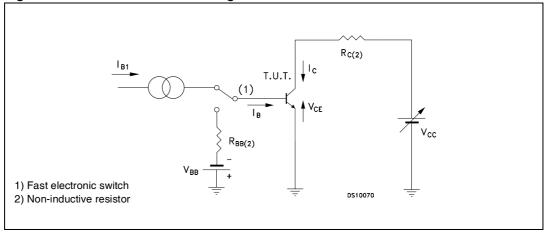
Figure 8. Inductive load storage time





2.2 Test circuits

Figure 10. Resistive load switching test circuit



1) Fast electronic switch
2) Non-inductive resistor
3) Fast recovery rectifier

Figure 11. Inductive load switching test circuit

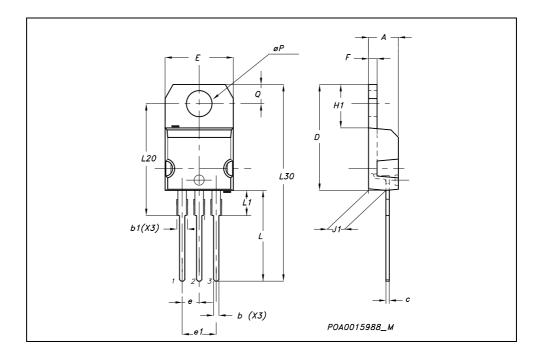
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3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-220 MECHANICAL DATA

DIM.		mm.			inch			
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α	4.40		4.60	0.173		0.181		
b	0.61		0.88	0.024		0.034		
b1	1.15		1.70	0.045		0.066		
С	0.49		0.70	0.019		0.027		
D	15.25		15.75	0.60		0.620		
Е	10		10.40	0.393		0.409		
е	2.40		2.70	0.094		0.106		
e1	4.95		5.15	0.194		0.202		
F	1.23		1.32	0.048		0.052		
H1	6.20		6.60	0.244		0.256		
J1	2.40		2.72	0.094		0.107		
L	13		14	0.511		0.551		
L1	3.50		3.93	0.137		0.154		
L20		16.40			0.645			
L30		28.90			1.137			
øΡ	3.75		3.85	0.147		0.151		
Q	2.65		2.95	0.104		0.116		



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Revision history BUL705

4 Revision history

Table 4. Revision history

Date	Revision	Changes
22-May-2006	1	Initial release.

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